

**ORIGINAL PATENT APPLICATION BASED ON:**

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## **CORRECTING POTENTIAL DEFECTS IN AN OLED DEVICE**

### **CROSS REFERENCE TO RELATED APPLICATIONS**

Reference is made to commonly assigned U.S. Patent Application Serial No. 10/141,587 filed May 8, 2002 by Michael L. Boroson et al., entitled  
5 “In-Situ Method for Making OLED Devices That Are Moisture or Oxygen-Sensitive”, and commonly assigned U.S. Patent Application Serial No. 10/021,410 filed December 12, 2001 by Bradley A. Phillips et al., entitled “Apparatus for Permitting Transfer of Organic Material From a Donor to Form a Layer in an OLED Device”, the disclosures of which are herein incorporated by reference.

### **FIELD OF THE INVENTION**

10 The present invention relates to making OLED devices which includes using radiation thermal transfer, and for identifying potential defects and correcting for such defects.

### **BACKGROUND OF THE INVENTION**

15 Organic light-emitting diodes (OLEDs, also known as organic light-emitting devices) are generally anticipated to overtake liquid crystal displays (LCDs) as the preferred display technology. This is expected because OLEDs enjoy a number of practical advantages over LCDs. Some of the most significant advantages include: 1) OLEDs have a brighter image that can be viewed from  
20 wider angles; 2) elimination of backlight required in LCDs lowers cost, increases reliability, and improves image intensity range, contrast, and consistency over the viewing area; 3) OLEDs require less power for equivalent image quality; 4) OLEDs are potentially cheaper to manufacture, requiring fewer materials and roughly half the number of manufacturing steps; and 5) OLEDs produce a wider  
25 spectrum of colors. However, OLED displays and their components known as OLED structures, which constitute subpixels of the display, are more currently difficult and costly to manufacture than LCD displays. It is a continuing focus of the industry to increase throughput in an effort to lower the cost of OLED manufacturing.

30 Conventional OLED display devices are built on glass substrates such that a two-dimensional OLED array for image manifestation is formed. The

basic OLED cell structure includes of a stack of thin organic layers sandwiched between an array of anodes and a common metallic cathode. The organic layers commonly comprise a hole-transporting layer (HTL), a light-emitting layer (LEL), and an electron-transporting layer (ETL). When an appropriate voltage is applied to the cell, the injected holes and electrons recombine in the LEL near the LEL-HTL interface to produce light (electroluminescence).

The LEL within a color OLED display device most commonly includes three different types of fluorescent or phosphorescent molecules that are repeated through the LEL. Red, green, and blue regions, or subpixels, are formed throughout the LEL during the manufacturing process to provide a two-dimensional array of pixels. Each of the red, green, and blue subpixel sets undergoes a separate patterned deposition, typically by evaporating a linear source through a shadow mask. Shadow masking is a well known technology, yet it is limited in both the precision of its deposition pattern, and the pattern's fill factor or aperture ratio; thus, incorporating shadow masking into OLED manufacturing limits the achievable sharpness and resolution of the resultant display. Radiation thermal transfer (RTT) promises significant advantages including a more precise deposition pattern and higher aperture ratio; however, it has proved challenging to adapt RTT to a high-throughput manufacturing line.

During RTT, a donor sheet having the desired organic material is placed into close proximity to the OLED substrate in a vacuum chamber. A source of radiation, such as a laser, impinges upon the donor sheet through a clear support to the donor sheet and is absorbed within a light-absorbing layer contained atop the support. The conversion of the radiation energy to heat sublimates the organic material that forms the top layer of the donor sheet and thereby transfers the organic material in a sharply defined subpixel pattern to the OLED substrate.

The quality of the RTT process is dependent on several key process and product parameters. Real-time knowledge of how these process and product parameters vary during manufacturing is an important aspect in making the RTT process repeatable and cost effective. What is needed is a way to measure key process and product parameters in-situ.

U.S. Patent 6,485,884 provides a method for patterning oriented materials to make OLED display devices, and also provides donor sheets for use with the method, as well as methods for making the donor sheets. However, U.S. Patent 6,485,884 patent fails to provide a system that enables in-situ monitoring of process and product parameters. To date, however, in-situ monitoring of process and product parameters has not been adapted to RTT.

### **SUMMARY OF THE INVENTION**

It is therefore an object of the present invention to measure and analyze key process and product parameters in laser thermal transfer for improving the yield and quality of OLED devices.

It is another object of the invention to ensure that transfer of donor material in radiation thermal transfer processing has occurred and is of sufficient quality to continue processing.

It is yet another object of the invention to provide a way to utilize in-situ measurement data to compensate and thus improve the yield and throughput of acceptable products through radiation thermal transfer.

This object is achieved by a method of making an OLED device that corrects for potential defect(s) identified in one processing station by adjusting a subsequent processing station, comprising:

- a) processing an OLED substrate by adding at least one organic layer and measuring in-situ one or more parameters associated with such organic layer to produce a signal representative of potential defect(s) in a produced OLED device; and
- b) adjusting in a subsequent processing station in response to the signal to change the formation of a subsequent organic layer added to the OLED device to compensate for the potential defect(s).

### **ADVANTAGES**

It is an advantage of this invention that it permits less waste and additional throughput in the manufacture of OLED devices, thus increasing the efficiency of the manufacturing process. In-situ monitoring is important in determining whether a transfer of material has occurred and in ensuring the quality

of the transfer. Further, in-situ monitoring eliminates any potential contamination that can occur during ex-situ testing. In-situ process and product parameter monitoring can enable compensations to be made in processes that occur downstream during the OLED manufacturing process, thereby improving yield and increasing throughput.

### **BRIEF DESCRIPTION OF THE DRAWINGS**

FIG. 1 shows a cross-sectional view of a pixel of an OLED device which can be used according to a first embodiment of the present invention;

FIG. 2 shows a cross-sectional representation of one embodiment of the structure of a donor that can be used in the method described herein;

FIG. 3 is a cross-sectional view of one embodiment of the placement of a donor against a substrate in accordance with this invention;

FIG. 4 is a cross-sectional representation of one embodiment of an apparatus that can be used to effect the method of this invention;

FIG. 5 illustrates a process flow in accordance with the present invention for the in-situ characterization of process parameters for a radiation thermal transfer deposition process;

FIG. 6 is a block diagram of one embodiment of a method of making an OLED device in accordance with this invention; and

FIG. 7 is a block diagram of another embodiment of a method of making an OLED device in accordance with this invention.

Since device feature dimensions such as layer thicknesses are frequently in sub-micrometer ranges, the drawings are scaled for ease of visualization rather than dimensional accuracy.

### **DETAILED DESCRIPTION OF THE INVENTION**

The term “display” or “display panel” is employed to designate a screen capable of electronically displaying video images or text. The term “pixel” is employed in its art-recognized usage to designate an area of a display panel that can be stimulated to emit light independently of other areas. The term “OLED device” is used in its art-recognized meaning of a display device comprising organic light-emitting diodes as pixels. A color OLED device emits light of at

least one color. The term “multicolor” is employed to describe a display panel that is capable of emitting light of a different hue in different areas. In particular, it is employed to describe a display panel that is capable of displaying images of different colors. These areas are not necessarily contiguous. The term “full color”  
5 is employed to describe multicolor display panels that are capable of emitting in the red, green, and blue regions of the visible spectrum and displaying images in any hue or combination of hues. The red, green, and blue colors constitute the three primary colors from which all other colors can be generated by appropriately mixing these three primaries. The term “hue” refers to the intensity profile of light  
10 emission within the visible spectrum, with different hues exhibiting visually discernible differences in color. The pixel or subpixel is generally used to designate the smallest addressable unit in a display panel. For a monochrome display, there is no distinction between pixel or subpixel. The term “subpixel” is used in multicolor display panels and is employed to designate any portion of a  
15 pixel which can be independently addressable to emit a specific color. For example, a blue subpixel is that portion of a pixel which can be addressed to emit blue light. In a full-color display, a pixel generally comprises three primary-color subpixels, namely blue, green, and red. For the purposes of this invention, the terms “pixel” and “subpixel” will be used interchangeably. The term “pitch” is  
20 used to designate the distance separating two pixels or subpixels in a display panel. Thus, a subpixel pitch means the separation between two subpixels.

Turning now to FIG. 1, there is shown a cross-sectional view of a pixel of an OLED device **10** which can be used according to a first embodiment of the present invention. In some embodiments, the pixel of OLED device **10** can be  
25 a subpixel as defined above. The pixel includes a substrate **15**, an anode **20** disposed over substrate **15**, and a cathode **50** spaced from anode **20**. An optional hole-injecting layer **25** is disposed over anode **20**, and hole-transporting layer **30** is disposed over hole-injecting layer **25**. A light-emitting layer **35** is disposed over the hole-transporting layer **30**. An electron-transporting layer **40** can be disposed  
30 over light-emitting layer **35**. These layers will be described in more detail.

Substrate **15** can be an organic solid, an inorganic solid, or a combination of organic and inorganic solids that provides a surface for receiving organic material from a donor. Substrate **15** can be rigid or flexible and can be processed as separate individual pieces, such as sheets or wafers, or as a continuous roll. Typical substrate materials include glass, plastic, metal, ceramic, semiconductor, metal oxide, semiconductor oxide, semiconductor nitride, or combinations thereof. Substrate **15** can be a homogeneous mixture of materials, a composite of materials, or multiple layers of materials. Substrate **15** can be an OLED substrate, that is a substrate commonly used for preparing OLED devices, e.g. active-matrix low-temperature polysilicon TFT substrate. The substrate **15** can either be light transmissive or opaque, depending on the intended direction of light emission. The light transmissive property is desirable for viewing the EL emission through the substrate. Transparent glass or plastic are commonly employed in such cases. For applications where the EL emission is viewed through the top electrode, the transmissive characteristic of the bottom support is immaterial, and therefore can be light transmissive, light absorbing or light reflective. Substrates for use in this case include, but are not limited to, glass, plastic, semiconductor materials, ceramics, and circuit board materials, or any others commonly used in the formation of OLED devices, which can be either passive-matrix devices or active-matrix devices.

An electrode is formed over substrate **15** and is most commonly configured as an anode **20**. When EL emission is viewed through the substrate **15**, anode **20** should be transparent or substantially transparent to the emission of interest. Common transparent anode materials useful in this invention are indium-tin oxide and tin oxide, but other metal oxides can work including, but not limited to, aluminum- or indium-doped zinc oxide, magnesium-indium oxide, and nickel-tungsten oxide. In addition to these oxides, metal nitrides such as gallium nitride, metal selenides such as zinc selenide, and metal sulfides such as zinc sulfide, can be used as an anode material. For applications where EL emission is viewed through the top electrode, the transmissive characteristics of the anode material are immaterial and any conductive material can be used, transparent, opaque or

reflective. Example conductors for this application include, but are not limited to, gold, iridium, molybdenum, palladium, and platinum. The preferred anode materials, transmissive or otherwise, have a work function of 4.1 eV or greater. Desired anode materials can be deposited by any suitable means such as evaporation, sputtering, chemical vapor deposition, or electrochemical means. Anode materials can be patterned using well known photolithographic processes.

While not always necessary, it is often useful that a hole-injecting layer **25** be formed over anode **20** in an organic light-emitting display. The hole-injecting material can serve to improve the film formation property of subsequent organic layers and to facilitate injection of holes into the hole-transporting layer. Suitable materials for use in hole-injecting layer **25** include, but are not limited to, porphyrinic compounds as described in U.S. Patent 4,720,432, and plasma-deposited fluorocarbon polymers as described in U.S. Patent 6,208,075. Alternative hole-injecting materials reportedly useful in organic EL devices are described in EP 0 891 121 A1 and EP 1,029,909 A1.

While not always necessary, it is often useful that a hole-transporting layer **30** be formed over the hole-injecting layer **25**, or over anode **20** if no hole-injecting layer is used. Desired hole-transporting materials can be deposited by any suitable means such as evaporation, sputtering, chemical vapor deposition, electrochemical means, thermal transfer, or laser thermal transfer from a donor material. Hole-transporting materials useful in hole-transporting layer **30** are well known to include compounds such as an aromatic tertiary amine, where the latter is understood to be a compound containing at least one trivalent nitrogen atom that is bonded only to carbon atoms, at least one of which is a member of an aromatic ring. In one form the aromatic tertiary amine can be an arylamine, such as a monoarylamine, diarylamine, triarylamine, or a polymeric arylamine. Exemplary monomeric triarylaminines are illustrated by Klupfel et al. in U.S. Patent 3,180,730. Other suitable triarylaminines substituted with one or more vinyl radicals and/or comprising at least one active hydrogen-containing group are disclosed by Brantley et al. in U.S. Patents 3,567,450 and 3,658,520.



A more preferred class of aromatic tertiary amines are those which include at least two aromatic tertiary amine moieties as described in U.S. Patents 4,720,432 and 5,061,569. Such compounds include those represented by structural Formula A.



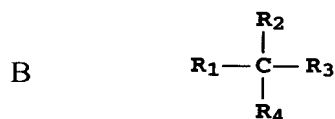
5 wherein:

Q<sub>1</sub> and Q<sub>2</sub> are independently selected aromatic tertiary amine moieties; and

G is a linking group such as an arylene, cycloalkylene, or alkylene group of a carbon to carbon bond.

In one embodiment, at least one of Q<sub>1</sub> or Q<sub>2</sub> contains a polycyclic fused ring structure, e.g., a naphthalene. When G is an aryl group, it is conveniently a  
10 phenylene, biphenylene, or naphthalene moiety.

A useful class of triarylamines satisfying structural Formula A and containing two triarylamine moieties is represented by structural Formula B.



where:

15 R<sub>1</sub> and R<sub>2</sub> each independently represent a hydrogen atom, an aryl group, or an alkyl group or R<sub>1</sub> and R<sub>2</sub> together represent the atoms completing a cycloalkyl group; and

R<sub>3</sub> and R<sub>4</sub> each independently represent an aryl group, which is in turn substituted with a diaryl substituted amino group, as indicated by structural

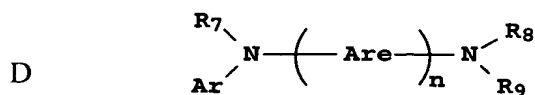
20 Formula C.



wherein R<sub>5</sub> and R<sub>6</sub> are independently selected aryl groups. In one embodiment, at least one of R<sub>5</sub> or R<sub>6</sub> contains a polycyclic fused ring structure, e.g., a naphthalene.

Another class of aromatic tertiary amines are the tetraaryldiamines. Desirable tetraaryldiamines include two diarylamino groups, such as indicated by

Formula C, linked through an arylene group. Useful tetraaryldiamines include those represented by Formula D.



wherein:

each Are is an independently selected arylene group, such as a phenylene  
5 or anthracene moiety;

n is an integer of from 1 to 4; and

Ar, R<sub>7</sub>, R<sub>8</sub>, and R<sub>9</sub> are independently selected aryl groups.

In a typical embodiment, at least one of Ar, R<sub>7</sub>, R<sub>8</sub>, and R<sub>9</sub> is a  
polycyclic fused ring structure, e.g., a naphthalene.

10 The various alkyl, alkylene, aryl, and arylene moieties of the foregoing structural Formulae A, B, C, D, can each in turn be substituted. Typical substituents include alkyl groups, alkoxy groups, aryl groups, aryloxy groups, and halogens such as fluoride, chloride, and bromide. The various alkyl and alkylene moieties typically contain from 1 to about 6 carbon atoms. The cycloalkyl moieties  
15 can contain from 3 to about 10 carbon atoms, but typically contain five, six, or seven carbon atoms--e.g., cyclopentyl, cyclohexyl, and cycloheptyl ring structures. The aryl and arylene moieties are usually phenyl and phenylene moieties.

The hole-transporting layer in an OLED device can be formed of a single or a mixture of aromatic tertiary amine compounds. Specifically, one can  
20 employ a triarylamine, such as a triarylamine satisfying the Formula B, in combination with a tetraaryldiamine, such as indicated by Formula D. When a triarylamine is employed in combination with a tetraaryldiamine, the latter is positioned as a layer interposed between the triarylamine and the electron-injecting and transporting layer. Illustrative of useful aromatic tertiary amines are  
25 the following:

1,1-Bis(4-di-*p*-tolylaminophenyl)cyclohexane

1,1-Bis(4-di-*p*-tolylaminophenyl)-4-phenylcyclohexane

4,4'-Bis(diphenylamino)quadriphenyl

Bis(4-dimethylamino-2-methylphenyl)-phenylmethane

- N,N,N-Tri(*p*-tolyl)amine  
 4-(di-*p*-tolylamino)-4'-[4(di-*p*-tolylamino)-styryl]stilbene  
 N,N,N',N'-Tetra-*p*-tolyl-4-4'-diaminobiphenyl  
 N,N,N',N'-Tetraphenyl-4,4'-diaminobiphenyl  
 5 N-Phenylcarbazole  
 Poly(N-vinylcarbazole)  
 N,N'-di-1-naphthalenyl-N,N'-diphenyl-4, 4'-diaminobiphenyl  
 4,4'-Bis[N-(1-naphthyl)-N-phenylamino]biphenyl  
 4,4''-Bis[N-(1-naphthyl)-N-phenylamino]*p*-terphenyl  
 10 4,4'-Bis[N-(2-naphthyl)-N-phenylamino]biphenyl  
 4,4'-Bis[N-(3-acenaphthenyl)-N-phenylamino]biphenyl  
 1,5-Bis[N-(1-naphthyl)-N-phenylamino]naphthalene  
 4,4'-Bis[N-(9-anthryl)-N-phenylamino]biphenyl  
 4,4''-Bis[N-(1-anthryl)-N-phenylamino]-*p*-terphenyl  
 15 4,4'-Bis[N-(2-phenanthryl)-N-phenylamino]biphenyl  
 4,4'-Bis[N-(8-fluoranthryl)-N-phenylamino]biphenyl  
 4,4'-Bis[N-(2-pyrenyl)-N-phenylamino]biphenyl  
 4,4'-Bis[N-(2-naphthacenyl)-N-phenylamino]biphenyl  
 4,4'-Bis[N-(2-perylenyl)-N-phenylamino]biphenyl  
 20 4,4'-Bis[N-(1-coronenyl)-N-phenylamino]biphenyl  
 2,6-Bis(di-*p*-tolylamino)naphthalene  
 2,6-Bis[di-(1-naphthyl)amino]naphthalene  
 2,6-Bis[N-(1-naphthyl)-N-(2-naphthyl)amino]naphthalene  
 N,N,N',N'-Tetra(2-naphthyl)-4,4''-diamino-*p*-terphenyl  
 25 4,4'-Bis{N-phenyl-N-[4-(1-naphthyl)-phenyl]amino}biphenyl  
 4,4'-Bis[N-phenyl-N-(2-pyrenyl)amino]biphenyl  
 2,6-Bis[N,N-di(2-naphthyl)amine]fluorene  
 1,5-Bis[N-(1-naphthyl)-N-phenylamino]naphthalene

Another class of useful hole-transporting materials includes  
 30 polycyclic aromatic compounds as described in EP 1 009 041. In addition,  
 polymeric hole-transporting materials can be used such as poly(N-vinylcarbazole)

(PVK), polythiophenes, polypyrrole, polyaniline, and copolymers such as poly(3,4-ethylenedioxythiophene)/poly(4-styrenesulfonate) also called PEDOT/PSS.

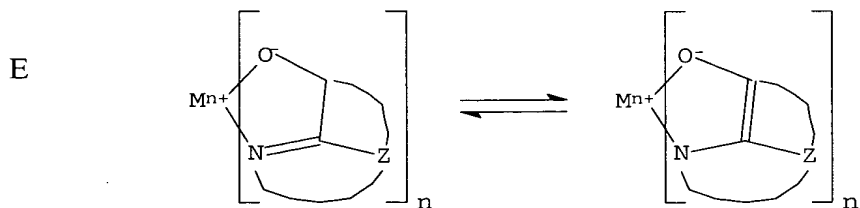
Light-emitting layer **35** produces light in response to hole-electron recombination. Light-emitting layer **35** is formed over anode **20** and over any other layers formed, such as hole-transporting layer **30**. Desired organic light-emitting materials can be deposited by any suitable means such as evaporation, sputtering, chemical vapor deposition, electrochemical means, or radiation thermal transfer from a donor material. Useful organic light-emitting materials are well known. As more fully described in U.S. Patents 4,769,292 and 5,935,721, the light-emitting layers of the organic EL element comprise a luminescent or fluorescent material where electroluminescence is produced as a result of electron-hole pair recombination in this region. The light-emitting layers can be comprised of a single material, but more commonly include a host material doped with a guest compound or dopant where light emission comes primarily from the dopant and can be of any color. The host materials in the light-emitting layers can be an electron-transporting material, as defined below, a hole-transporting material, as defined above, or another material that supports hole-electron recombination. The dopant is usually chosen from highly fluorescent dyes, but phosphorescent compounds, e.g., transition metal complexes as described in WO 98/55561, WO 00/18851, WO 00/57676, and WO 00/70655 are also useful. Dopants are typically coated as 0.01 to 10% by weight into the host material.

An important relationship for choosing a dye as a dopant is a comparison of the bandgap potential which is defined as the energy difference between the highest occupied molecular orbital and the lowest unoccupied molecular orbital of the molecule. For efficient energy transfer from the host material to the dopant molecule, a necessary condition is that the band gap of the dopant is smaller than that of the host material.

Host and emitting molecules known to be of use include, but are not limited to, those disclosed in U.S. Patents 4,768,292; 5,141,671; 5,150,006;

5,151,629; 5,294,870; 5,405,709; 5,484,922; 5,593,788; 5,645,948; 5,683,823;  
5,755,999; 5,928,802; 5,935,720; 5,935,721; and 6,020,078.

Metal complexes of 8-hydroxyquinoline and similar derivatives (Formula E) constitute one class of useful host materials capable of supporting  
5 electroluminescence, and are particularly suitable for light emission of wavelengths longer than 500 nm, e.g., green, yellow, orange, and red.



wherein:

M represents a metal;

n is an integer of from 1 to 3; and

10 Z independently in each occurrence represents the atoms completing a nucleus having at least two fused aromatic rings.

From the foregoing it is apparent that the metal can be a monovalent, divalent, or trivalent metal. The metal can, for example, be an alkali metal, such as lithium, sodium, or potassium; an alkaline earth metal, such as  
15 magnesium or calcium; or an earth metal, such as boron or aluminum. Generally any monovalent, divalent, or trivalent metal known to be a useful chelating metal can be employed.

Z completes a heterocyclic nucleus containing at least two fused aromatic rings, at least one of which is an azole or azine ring. Additional rings,  
20 including both aliphatic and aromatic rings, can be fused with the two required rings, if required. To avoid adding molecular bulk without improving on function the number of ring atoms is usually maintained at 18 or less.

Illustrative of useful chelated oxinoid compounds are the following:

25 CO-1: Aluminum trisoxine [alias, tris(8-quinolinolato)aluminum(III)]  
CO-2: Magnesium bisoxine [alias, bis(8-quinolinolato)magnesium(II)]

CO-3: Bis[benzo{f}-8-quinolinolato]zinc (II)

CO-4: Bis(2-methyl-8-quinolinolato)aluminum(III)-μ-oxo-bis(2-methyl-8-quinolinolato) aluminum(III)

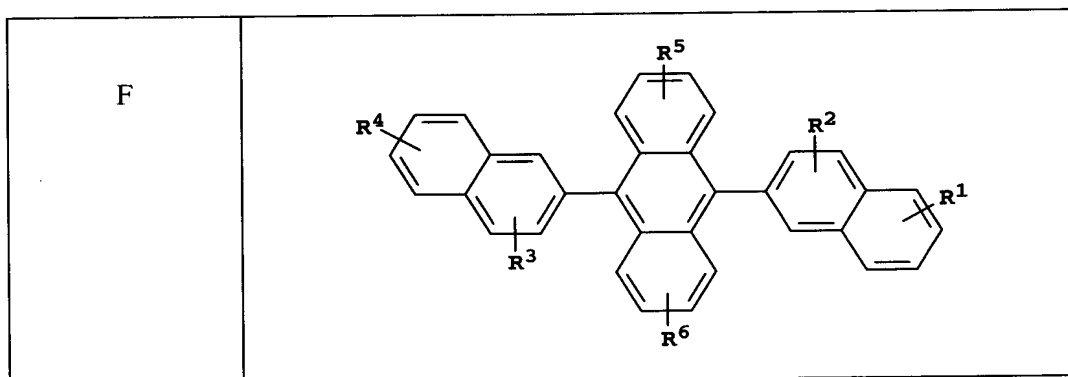
CO-5: Indium trisoxine [alias, tris(8-quinolinolato)indium]

5 CO-6: Aluminum tris(5-methyloxine) [alias, tris(5-methyl-8-quinolinolato) aluminum(III)]

CO-7: Lithium oxine [alias, (8-quinolinolato)lithium(I)]

Derivatives of 9,10-di-(2-naphthyl)anthracene (Formula F)

constitute one class of useful host materials capable of supporting  
10 electroluminescence, and are particularly suitable for light emission of  
wavelengths longer than 400 nm, e.g., blue, green, yellow, orange or red.



wherein  $R^1$ ,  $R^2$ ,  $R^3$ ,  $R^4$ ,  $R^5$ , and  $R^6$  represent one or more substituents on each ring  
where each substituent is individually selected from the following groups:

15 Group 1: hydrogen, or alkyl of from 1 to 24 carbon atoms;

Group 2: aryl or substituted aryl of from 5 to 20 carbon atoms;

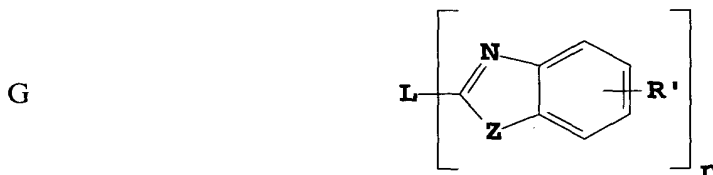
Group 3: carbon atoms from 4 to 24 necessary to complete a fused  
aromatic ring of anthracenyl, pyrenyl, or perylenyl;

Group 4: heteroaryl or substituted heteroaryl of from 5 to 24 carbon atoms  
20 as necessary to complete a fused heteroaromatic ring of furyl, thienyl, pyridyl,  
quinolinyl or other heterocyclic systems;

Group 5: alkoxyamino, alkylamino, or arylamino of from 1 to 24 carbon  
atoms; and

Group 6: fluorine, chlorine, bromine or cyano.

Benzazole derivatives (Formula G) constitute another class of useful host materials capable of supporting electroluminescence, and are particularly suitable for light emission of wavelengths longer than 400 nm, e.g., blue, green, yellow, orange or red.



5 where:

n is an integer of 3 to 8;

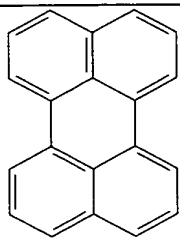
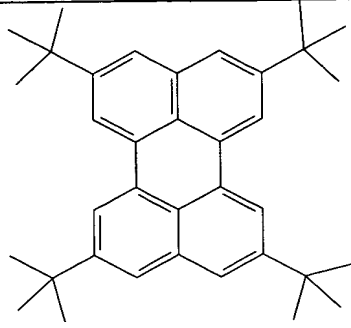
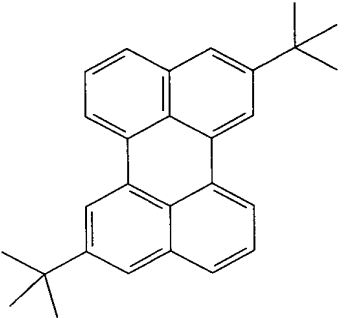
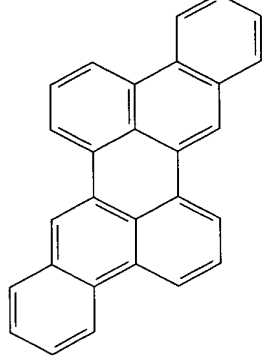
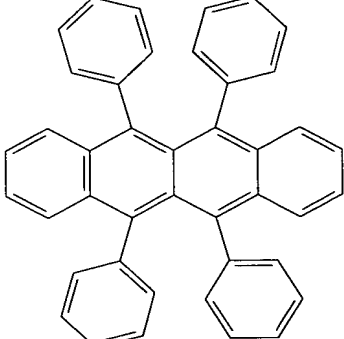
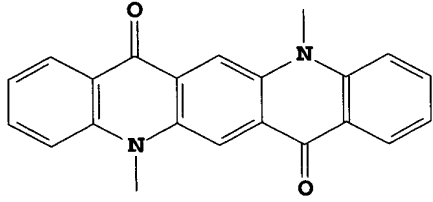
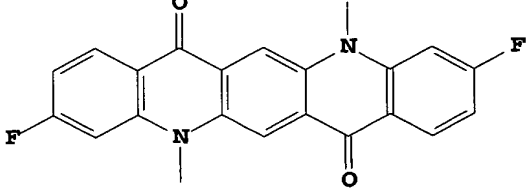
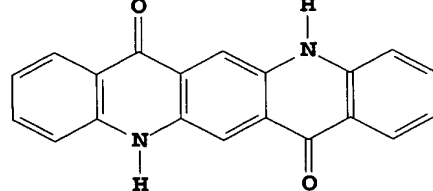
Z is O, NR or S;

R' is hydrogen; alkyl of from 1 to 24 carbon atoms, for example, propyl, t-butyl, heptyl, and the like; aryl or heteroatom substituted aryl of from 5 to 20  
10 carbon atoms for example phenyl and naphthyl, furyl, thienyl, pyridyl, quinolinyl and other heterocyclic systems; or halo such as chloro, fluoro; or atoms necessary to complete a fused aromatic ring; and

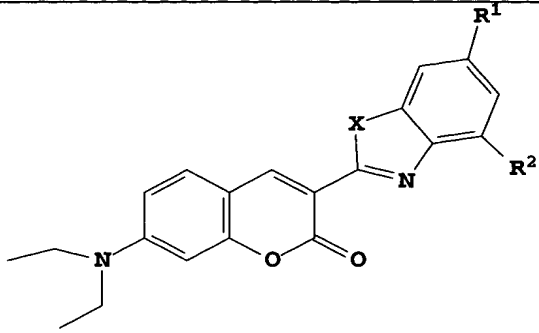
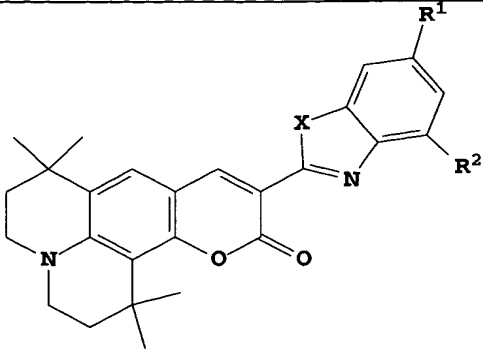
L is a linkage unit including alkyl, aryl, substituted alkyl, or substituted aryl, which conjugately or unconjugately connects the multiple benzazoles  
15 together.

An example of a useful benzazole is 2, 2', 2''-(1,3,5-phenylene)tris[1-phenyl-1H-benzimidazole].

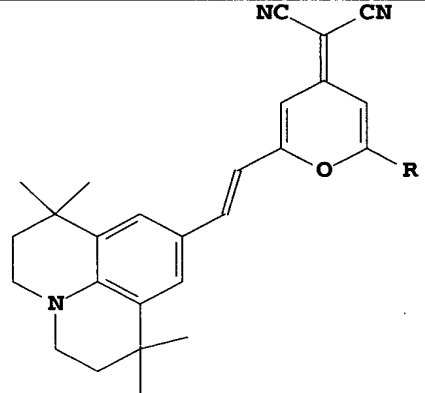
Desirable fluorescent dopants include derivatives of anthracene, tetracene, xanthene, perylene, rubrene, coumarin, rhodamine, quinacridone,  
20 dicyanomethylenepyran compounds, thiopyran compounds, polymethine compounds, pyrilium and thiapyrilium compounds, and carbostyryl compounds. Illustrative examples of useful dopants include, but are not limited to, the following:

 <p>L1</p>	 <p>L2</p>
 <p>L3</p>	 <p>L4</p>
 <p>L5</p>	 <p>L6</p>
 <p>L7</p>	 <p>L8</p>

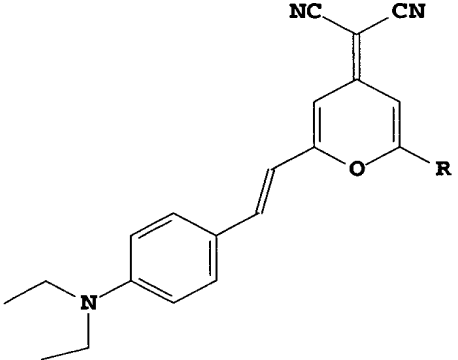


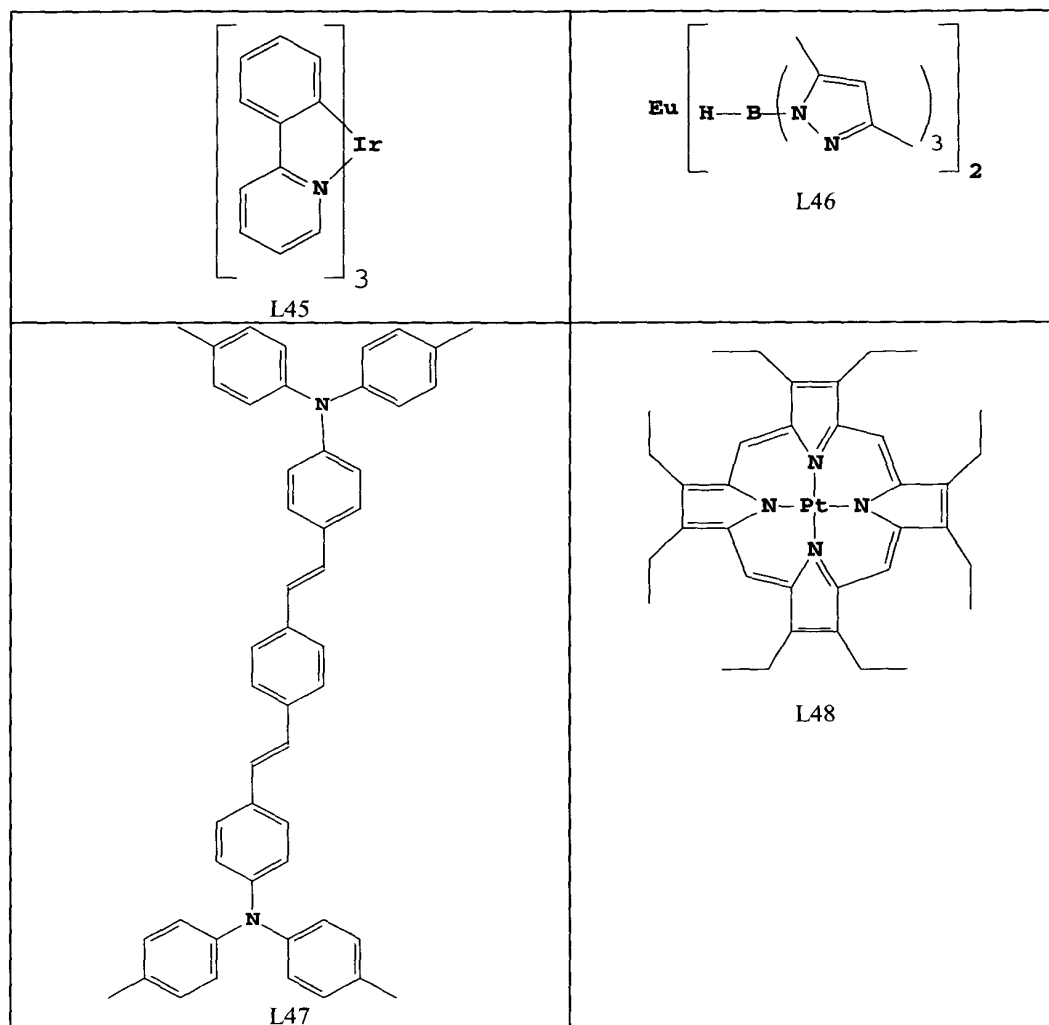
							
	<u>X</u>	<u>R1</u>	<u>R2</u>		<u>X</u>	<u>R1</u>	<u>R2</u>
L9	O	H	H	L23	O	H	H
L10	O	H	Methyl	L24	O	H	Methyl
L11	O	Methyl	H	L25	O	Methyl	H
L12	O	Methyl	Methyl	L26	O	Methyl	Methyl
L13	O	H	t-butyl	L27	O	H	t-butyl
L14	O	t-butyl	H	L28	O	t-butyl	H
L15	O	t-butyl	t-butyl	L29	O	t-butyl	t-butyl
L16	S	H	H	L30	S	H	H
L17	S	H	Methyl	L31	S	H	Methyl
L18	S	Methyl	H	L32	S	Methyl	H
L19	S	Methyl	Methyl	L33	S	Methyl	Methyl
L20	S	H	t-butyl	L34	S	H	t-butyl
L21	S	t-butyl	H	L35	S	t-butyl	H
L22	S	t-butyl	t-butyl	L36	S	t-butyl	t-butyl

		
	<u>R</u>	
L37	phenyl	
L38	methyl	
L39	t-butyl	
L40	mesityl	

		
	<u>R</u>	
L41	phenyl	
L42	methyl	
L43	t-butyl	
L44	mesityl	



Other organic emissive materials can be polymeric substances, e.g. polyphenylenevinylene derivatives, dialkoxy-polyphenylenevinylenes, poly-para-phenylene derivatives, and polyfluorene derivatives, as taught by Wolk et al. in

5 commonly assigned U.S. Patent 6,194,119 B1 and references cited therein.

Although not shown, the device can additionally comprise more than two emissive layers, if such is desired for proper emissive properties of the resulting OLED device.

While not always necessary, it is often useful that an electron-

10 transporting layer **40** be formed over light-emitting layer **35**. Desired electron-transporting materials can be deposited by any suitable means such as evaporation,

sputtering, chemical vapor deposition, electrochemical means, thermal transfer, or laser thermal transfer from a donor material. Preferred electron-transporting materials for use in electron-transporting layer **40** are metal chelated oxinoid compounds, including chelates of oxine itself (also commonly referred to as 8-quinolinol or 8-hydroxyquinoline). Such compounds help to inject and transport electrons and exhibit both high levels of performance and are readily fabricated in the form of thin films. Exemplary of contemplated oxinoid compounds are those satisfying structural Formula E, previously described.

Other electron-transporting materials include various butadiene derivatives as disclosed in U.S. Patent 4,356,429 and various heterocyclic optical brighteners as described in U.S. Patent 4,539,507. Benzazoles satisfying structural Formula G are also useful electron-transporting materials.

Other electron-transporting materials can be polymeric substances, e.g. polyphenylenevinylene derivatives, poly-para-phenylene derivatives, polyfluorene derivatives, polythiophenes, polyacetylenes, and other conductive polymeric organic materials such as those listed in *Handbook of Conductive Molecules and Polymers*, Vols. 1-4, H.S. Nalwa, ed., John Wiley and Sons, Chichester (1997).

It will be understood that, as is common in the art, some of the layers described above can have more than one function. For example, light-emitting layer **35** can have hole-transporting properties or electron-transporting properties as desired for performance of the OLED device. Hole-transporting layer **30** or electron-transporting layer **40**, or both, can have emitting properties. In such a case, fewer layers can be sufficient for the desired emissive properties.

Cathode **50** is formed over the electron-transporting layer **40** or over light-emitting layers **35** if an electron-transporting layer is not used. When light emission is through the anode **20**, the cathode material can be comprised of nearly any conductive material. Desirable materials have good film-forming properties to ensure good contact with the underlying organic layer, promote electron injection at low voltage, and have good stability. Useful cathode materials often contain a low work function metal ( $< 3.0$  eV) or metal alloy. One preferred

cathode material is comprised of a Mg:Ag alloy wherein the percentage of silver is in the range of 1 to 20%, as described in U.S. Patent 4,885,221. Another suitable class of cathode materials includes bilayers comprised of a thin layer of a low work function metal or metal salt capped with a thicker layer of conductive metal.

5 One such cathode is comprised of a thin layer of LiF followed by a thicker layer of Al as described in U.S. Patent 5,677,572. Other useful cathode materials include, but are not limited to, those disclosed in U.S. Patents 5,059,861; 5,059,862; and 6,140,763.

When light emission is viewed through the cathode, the cathode

10 must be transparent or nearly transparent. For such applications, metals must be thin or one must use transparent conductive oxides, or a combination of these materials. Optically transparent cathodes have been described in more detail in U.S. Patent 5,776,623. Cathode materials can be deposited by evaporation, sputtering, or chemical vapor deposition. When needed, patterning can be

15 achieved through many well known methods including, but not limited to, through-mask deposition, integral shadow masking as described in U.S. Patent 5,276,380 and EP 0 732 868, laser ablation, and selective chemical vapor deposition.

Cathode **50** is an electrode vertically spaced apart from anode **20**.

20 Cathode **50** can be part of an active matrix device and in that case is a single electrode for the entire display. Alternatively, cathode **50** can be part of a passive matrix device, in which each cathode **50** can activate a column of pixels, and cathodes **50** are arranged orthogonal to anodes **20**.

An electron-injecting layer can also be present between the cathode

25 and the electron-transporting layer. Examples of electron-injecting materials include alkali halide salts, such as LiF mentioned above.

Turning now to FIG. 2, there is shown a cross-sectional representation of one embodiment of the structure of a donor **60** that can be used in the method and apparatus described herein. Donor **60** can be formed in a sheet

30 or as a continuous roll. Donor **60** includes at the minimum a support **72** that is preferably flexible, which comprises non-transfer surface **63**. Support **72** is first

uniformly coated with radiation-absorbing layer **74** that includes a radiation-absorbing material capable of absorbing radiation in a predetermined portion of the spectrum to produce heat so as to cause the transfer of organic material, then coated with a layer of heat-transferable organic material **70**. Support **72** then  
5 comprises non-transfer surface **63** of donor **60** and organic material **70** comprises transfer surface **65** of donor **60**. Radiation-absorbing layer **74** is capable of absorbing radiation in a predetermined portion of the spectrum thereby producing heat. The radiation-absorbing material can be a dye such as the dyes specified in U.S. Patent 5,578,416, a pigment such as carbon, or a metal such as nickel,  
10 chromium, titanium, etc.

Support **72** can be made of any of several materials which meet at least the following requirements. It must be capable of maintaining its structural integrity during the organic material transfer step while it is pressurized on one side, and during any pre-treat heating steps contemplated to remove volatile  
15 constituents such as water vapor. Additionally, support **72** must be capable of receiving on one surface a relatively thin coating of organic material **70**, and of retaining this coating without degradation during anticipated storage periods of the coated support (donor **60**). Support materials meeting these requirements include, for example, metal foils, certain plastic foils which exhibit a glass transition  
20 temperature value higher than a support temperature value anticipated to cause transfer of the transferable organic material **70** coated on support **72**, and fiber-reinforced plastic foils. While selection of suitable support materials can rely on known engineering approaches, it will be appreciated that certain aspects of a selected support material merit further consideration when configured as a donor  
25 support useful in the practice of the invention. For example, support **72** can require a multi-step cleaning and surface preparation process prior to precoating with radiation-absorbing layer **74** or organic material **70**.

FIG. 3 shows a cross-section view of one embodiment of the placement of donor **60** against substrate **15** in accordance with this invention. In  
30 this embodiment, receiving surface **86** of substrate **15** is uneven due to the presence of thin-film transistors **80**. Thin-film transistors **80** are separated in

substrate **15** by raised surface portions **82** as a result of the multilayer construction of each pixel or subpixel. This is described by Tang in commonly assigned U.S. Patent 5,937,272, the disclosure of which is incorporated herein by reference. The presence of raised surface portions **82** maintains the separation of gap **84** against  
5 the pressure that is exerted by the pressurizing fluid against non-transfer surface **63** and maintains a separation between portions of donor **60** and substrate **15**.

FIG. 3 also shows the process of using radiation to transfer organic material **70** from donor **60** to portions of substrate **15**. A pattern of radiation such as laser light beam **62** irradiates non-transfer surface **63**. Heat **90** is produced when  
10 laser light beam **62** strikes radiation-absorbing layer **74**, permitting heat **90** to be absorbed by organic material **70** in the immediate vicinity of laser light beam **62**, which causes the transfer of organic material **70** to substrate **15**. A large portion of the light impinging on donor **60** will be converted to heat, but this will only happen at selectively irradiated portions of donor **60**. Some or all of the heated  
15 portion of organic material **70** undergoes organic material transfer, that is, it is sublimed, vaporized, or ablated and becomes organic layer **92** on receiving surface **86** of substrate **15** in a patterned transfer.

Defects are possible during this process. For example, a portion of organic material **70** can be missing or of a reduced thickness, thus being a defect  
20 in donor **60**. Such a defective portion of donor **60** can lead to a defect in organic layer **92** upon the radiation thermal transfer process. Also, an inefficient radiation thermal transfer process can lead to incomplete organic material transfer and a defect in organic layer **92** on OLED substrate **15**. For example, the thickness of organic layer **92** can be insufficient for proper electroluminescence. Such a defect  
25 in organic layer **92** will also be referred to herein as a potential defect in the produced OLED device.

Turning now to FIG. 4, we see a cross-sectional representation of one embodiment of an apparatus that can be used to effect the method of this invention in which an OLED substrate **15** is coated in three processing stations in  
30 the same controlled environment coater **100**. Controlled environment coater **100** is an enclosed apparatus described herein that permits an in-situ method for

fabricating an OLED device under controlled-environment conditions and includes unitary housing **110** which encompasses three coating stations, at least one of which is a radiation thermal transfer station, a measurement station, and one or more robots. By controlled environment, we mean that the water vapor

5 partial pressure is preferably 1 Torr or less, or the oxygen partial pressure is preferably 1 Torr or less, or both. This can be accomplished by maintaining a vacuum inside the controlled environment coater **100**. This can also be accomplished by maintaining a water vapor level of preferably 1000 ppm or less, or an oxygen level of preferably 1000 ppm or less, or both, at a total pressure

10 greater than 1 Torr inside controlled environment coater **100**. While controlled environment coater **100** is shown as a single chamber, it can also include two or more chambers in which at least one chamber is maintained under a vacuum, and at least one chamber is maintained under a higher-pressure controlled environment as described above. Such an apparatus has been described previously in commonly

15 assigned U.S. Patent Application Serial No. 10/141,587 filed May 8, 2002 by Michael L. Boroson et al., entitled "In-Situ Method for Making OLED Devices That Are Moisture or Oxygen-Sensitive", the disclosure of which is herein incorporated by reference. While it is impossible to reduce the quantities of water vapor and/or oxygen completely to zero, controlled environment conditions can

20 reduce the quantities of these components to very low or imperceptible levels, such as 0.001 ppm. Controlling the environment can be achieved by various well known methods, e.g. oxygen or water-vapor scrubbers, or the use of purified gasses. Controlled environment coater **100** can include one chamber, or any number of chambers that can be connected by load locks or similarly-acting

25 apparatus such as tunnels or buffer chambers, whereby donor elements and receiver elements can be transported without exposure to moisture and/or oxygen. The conditions are maintained in controlled environment coater **100** by a means for controlling the atmosphere, e.g. controlled environment source **112**. Controlled environment coater **100** can include load lock **114**, which is used to load substrates

30 **15**, and load lock **116**, which is used to unload completed OLED devices. Several embodiments of controlled environment coater **100** have been more fully

described in commonly assigned U.S. Patent Application Serial No. 10/141,587 filed May 8, 2002 by Michael L. Boroson et al., entitled "In-Situ Method for Making OLED Devices That Are Moisture or Oxygen-Sensitive", the disclosure of which is herein incorporated by reference.

5                   The interior of this embodiment of controlled environment coater **100** can include coating station **120**, robots **122** and **128**, radiation thermal transfer station **124**, measurement station **126**, and coating station **130**. Coating station **120**, radiation thermal transfer station **124**, and coating station **130** are processing stations. In this embodiment, the stations are sequentially positioned in line, so  
10   that a substrate **15** can be sequentially moved in line through the different stations. Coating station **120** is a means for coating one or more organic layers over a substrate **15** e.g. a structure for applying a hole-transporting material over the substrate **15** by e.g. vapor deposition or other substantially uniform means. Coating means or coating apparatus **134** can represent e.g. a heated boat, a point  
15   vapor source, etc. It will be understood that other coating methods are possible, e.g. solvent coating, and that the relative positions of substrate **15** above or below coating apparatus **134** will depend on the type of coating. Coating station **120** can coat one or more organic layers on substrate **15**. For example, the use of two or more coating apparatus **134**, movable in relation to substrate **15**, will permit  
20   multiple organic layers to be coated.

                  Controlled environment coater **100** also includes a robot **122**. Robot **122** is an actuable robot control means for grasping and removing substrate **15** from coating station **120** after substrate **15** has been coated, and positioning coated substrate **15** into radiation thermal transfer station **124** so that it is in a  
25   material transferring relationship with donor **60**. For the purposes of this discussion, a robot shall include the apparatus necessary to move a web in the case where substrate **15** is in the form of a continuous web or roll. Robot **122** can include a grasping means **131** by which it can grasp and remove substrate **15** from coating station **120** and position the coated substrate **15** in radiation thermal  
30   transfer station **124**.



Radiation thermal transfer station **124** is a processing station that processes OLED substrate **15** by adding at least one organic layer by a radiation thermal transfer process. It can hold substrate **15** in a material transferring relationship with donor **60**, which includes light-emitting organic material.

5    Radiation thermal transfer station **124** can be e.g. an apparatus such as that described in commonly assigned U.S. Patent Application Serial No. 10/021,410 filed December 12, 2001 by Bradley A. Phillips et al., entitled "Apparatus for Permitting Transfer of Organic Material From a Donor to Form a Layer in an OLED Device", the disclosures of which are herein incorporated by reference.

10    Radiation thermal transfer station **124** is shown for convenience in the closed configuration, but it also has an open configuration in which the donor **60** and substrate **15** loading and unloading occurs. By material transferring relationship we mean the coated side of donor **60** is positioned in close contact with the receiving surface of substrate **15** and held in place by a means such as fluid

15    pressure in a pressure chamber, as described by Phillips, et al. Radiation thermal transfer station **124** is constructed so as to facilitate forming an emissive layer on substrate **15** through the selective transfer of organic material from donor **60** to substrate **15** by applying radiation from an actuable radiation means, e.g. laser light beam **62** from laser **138**, through transparent portion **146**. Radiation thermal

20    transfer is herein defined as any mechanism such as sublimation, ablation, vaporization or other process whereby material can be transferred upon initiation by radiation. The irradiation of donor **60** in a predetermined pattern selectively transfers one or more layers of coated material from donor **60** to substrate **15** so that material will coat selected portions of substrate **15**, as described by Phillips et

25    al.

Controlled environment coater **100** also includes measurement station **126**, which includes measurement apparatus **140**. Measurement apparatus **140** is an apparatus capable of measuring in-situ one or more parameters (e.g. thickness) associated with an organic layer such as light-emitting layer **35** coated

30    on OLED substrate **15** to produce a signal representative of potential defects in OLED device **10**. Measurement apparatus **140** can thereby identify potential

defects in one processing station (e.g. radiation thermal transfer station **124**) and produce a signal representative of the potential defects. Such a measurement apparatus **140** can be e.g. in-situ spectroscopic ellipsometry, which is commercially available from J.A. Woolam Co., Inc., and others. Other methods of measurement are also possible, and can include destructive tests that are performed on test sites that will not be utilized in the final OLED display device (e.g. near the edge of a panel), or non-destructive tests that can be performed anywhere on OLED substrate **15**. Destructive in-situ tests that can be performed on test sites can include photoluminescence to check the quality of the transferred material layer, Kelvin probe testing to measure the work function of the transferred material layer, atomic force microscopy (AFM) tests to determine the thickness and resolution of the transferred material layer, laser desorption mass spectroscopy to determine impurities, micro-Raman spectroscopy, X-ray fluorescence, or four point probe measurements. Nondestructive in-situ tests can include diffracting a laser beam off of a set of lines that form a grating, or ellipsometry on the transferred material to ascertain transfer layer thickness and density.

Controlled environment coater **100** also includes coating station **130**, which is a means for forming an electron-transporting layer over the first and second organic layers of emissive coated substrate **15** that had been previously coated in coating station **120** and radiation thermal transfer station **124**. Coating apparatus **148** can represent e.g. one or more heated boats for vaporizing materials to form the desired layer.

These operations can be simultaneous at the various stations. For example, a substrate **15** can undergo radiation thermal transfer at radiation thermal transfer station **124**, while a previously-transferred substrate **15** is being coated at coating station **130**, another previously-transferred substrate **15** is being measured at measurement station **126**, and an uncoated substrate **15** is being coated at coating station **120**.

A process control means, e.g. computer **150** can be arranged to control this process via data input/outputs **152**, **154**, **156**, and **158**. Robots **122** and

**128** can be controlled by computer **150** via data input/outputs **152** and **158**, respectively. Of particular importance to this method is that computer **150** controls measurement apparatus **140**, and receives a signal representative of potential defects in coated substrate **15**, via data input/output **154**. Computer **150** can then  
5 adjust one or more subsequent steps or one or more subsequent processing stations in response to the signal to change the formation of a subsequent organic layer added to OLED substrate **15** to compensate for potential defects. For example, if a defect is detected in substrate **15** by measurement apparatus **140**, computer **150** can adjust the subsequent processing station, that is coating station **130**, in  
10 response to the defect signal, thereby changing the formation of the subsequent organic layer (e.g. the electron-transporting layer **40**) added to OLED substrate **15** at coating station **130**. For example, if the signal from measurement apparatus **140** indicates an undesired thickness of the OLED layer(s), computer **150** can adjust the thickness of the subsequent organic layer deposited at coating station **130**.  
15 Such adjustment can be effected by e.g. changing the rate of vaporization from coating apparatus **148**, or by changing the residence time of OLED substrate **15** in coating station **130**.

Alternatively, computer **150** can control robot **128** to reject the device if there is a defect, e.g. if insufficient organic material was transferred, so  
20 that OLED substrate **15** is not passed to coating station **130**, but is removed from the system. Alternatively, computer **150** can control robot **128** to transfer the rejected device to a reworking station that can rework rejected OLED substrate **15** to correct for identified defects, e.g. to correct for insufficient organic material transfer. A reworking station can be an additional station, or can be radiation  
25 thermal transfer station **124** to which substrate **15** can be returned for reworking to correct for identified defects, such reworking can include radiation thermal transfer of an organic layer to the defective locations of substrate **15** using an additional donor **60**.

Although not shown, computer **150** can also be a process control  
30 means for controlling in a time sequence the actuation of the coating means, that is

stations **120**, **124**, and **130**, respectively. Computer **150** can also control the actuatable radiation means, that is laser **138**.

Although FIG. 4 shows a system comprising three coating stations and one measurement station in a particular order, those skilled in the art will understand that this invention is not limited to this arrangement. For example, a measurement station can be located before radiation thermal transfer station **124** for testing donor **60**. Such an arrangement would permit a donor **60** with defects or defective portions to be rejected before it is used to produce an unacceptable OLED device from OLED substrate **15**. Alternatively, the identified defective portions of donor **60** can be excluded in the process to form an organic layer on OLED substrate **15**, thus transferring organic material **70** only from acceptable portions of donor **60** and reducing waste for OLED substrates **15**. This is a particularly effective method if donor **60** is in the form of a continuous web, but can also be used if donor **60** is in the form of sheets. Particularly effective methods for testing donor **60** in this invention include in-situ spectroscopic ellipsometry, automated image analysis, and automated absorption and transmission measurements.

FIG. 5 illustrates a process flow **200** in accordance with the present invention for the in-situ characterization of process parameters for a radiation thermal transfer deposition process. Process flow **200** includes a donor support **72** that can be a continuous roll of extruded web that is, in one example, 3 mils thick, 22 inches wide, and hundreds of yards long; alternately, donor support **72** can be a plurality of precut and framed donor sheets. Although donor support **72** has been quality control-tested prior to being supplied to process flow **200**, additional testing can be desirable in order to ascertain moisture content, contamination, deformities such as pinholes or non-uniform areas in the chromium light-absorbing layer, the thicknesses of the light-absorbing and antireflecting layers, etc. Therefore, donor support **72** can be subjected to one or more uncoated donor support tests **215** for testing donor support **72**, which can include Fourier transform infrared spectroscopy (FTIR), that can provide moisture content information about donor support **72**. A set of parametric data **220** for process

feedback and a go/no-go mark **225** are derived from uncoated donor support tests **215**. Go/no-go mark **225** can be e.g. a physical marking of good or bad sections, or can be computerized tracking of good or bad sections or parts.

Process flow **200** further includes a donor support deposition system **230**, in which donor support **72** receives an organic coating that is used several steps later in process flow **200** during radiation thermal transfer to deposit organic material to an OLED substrate **15**. Some examples of donor support deposition system **230** have been described by Boroson et al in commonly assigned U.S. Patent 6,555,284, the contents of which are incorporated by reference. Process flow **200** can further include one or more coated donor tests **235** for testing donor **60**, which can include Fourier transform infrared spectroscopy (FTIR), that can provide moisture content information about donor support **72**, and ellipsometry, that can determine layer thicknesses of organic material **70**, from which a set of parametric data **240** for process feedback and a go/no-go mark **245** are derived.

Process flow **200** further includes a radiation thermal transfer station **124** that transfers organic material **70** from the donor **60** to OLED substrate **15** using a radiation thermal transfer vacuum deposition process. Outputs from radiation thermal transfer station **124** include a post-RTT (post-radiation thermal transfer) OLED substrate **260** and a used donor support **265**. Post-RTT OLED substrate **260** is the article of manufacture that results from the radiation thermal transfer deposition of organic material to OLED substrate **15**. Used donor support **265** is the remains of the coated donor **60** after the radiation thermal transfer process.

Process flow **200** can further include: one or more first in-situ tests **270** that are performed upon post-RTT OLED substrate **260** for testing organic layer **92** from which a first set of data **275** is obtained, and one or more second in-situ tests **280** that are performed upon used donor support **265** and from which a second set of data **285** is obtained. Process flow **200** can further include post-RTT processing **290** that is performed upon post-RTT OLED substrate **260**.

In operation, donor support **72** is manufactured offsite and supplied to process flow **200**. Uncoated donor support tests **215** are conducted and result in parametric data **220**, which can be used to determine which portions of donor support **72** are acceptable for further processing. The acceptable portions of donor support **72**, and defective portions of donor support **72** can be noted in the memory of a software program (not shown) or can be used to provide a go/no-go mark **225** to donor support **72**. Donor support **72** next enters donor support deposition system **230**. Support **72** is coated to form donor **60**. One or more coated donor tests **235** are subsequently performed on donor **60**. The results of coated donor tests **235** are used to produce process control parametric data **240** and further can be used to provide a go/no-go mark **245** to donor **60**. Coated donor tests **235** can include ellipsometry to determine the thicknesses of organic layer **92**, material properties of the organic layer, dopant, and host concentrations, the presence of contaminants, etc. Using an area of donor **60** that is not going to be utilized for radiation thermal transfer enables coated donor tests **235** to include destructive testing methods such as photoluminescence or laser desorption mass spectroscopy. Defective portions of donor **60** as ascertained by parametric data **220** and **240** can be indexed and discarded later, enabling the translation of the defective portions of donor **60** to be sped up through the subsequent deposition processes. Alternately, if donor **60** is in the form of framed donor sheets, defective donors **60** can be discarded immediately.

Donor **60** next enters radiation thermal transfer station **124**, in which the organic material **70** of donor **60** is transferred to OLED substrate **15**. OLED substrate **15** can include previously deposited and tested layers, such as a hole-injecting layer and a hole-transporting layer as have been described above. Upon completion of the radiation thermal transfer processing, post-RTT OLED substrate **260** undergoes one or more first in-situ tests **270** from which first set of data **275** is derived. Concurrently, used donor support **265** undergoes one or more second in-situ tests **280** from which second set of data **285** is derived.

First in-situ tests **270** can occur within radiation thermal transfer station **124**, e.g., by directing a laser beam through transparent portion **146** of

radiation thermal transfer station **124** and onto the layer deposited atop OLED substrate **15**, or subsequent to radiation thermal transfer station **124** such as in measurement station **126**, and can include destructive tests performed on test sites that will not be utilized in the final OLED display device, such as near the edge of a panel, or nondestructive tests performed anywhere on post-RTT OLED substrate **260**.

Destructive first in-situ tests **270** that are performed on test sites can include photoluminescence to check the quality of the transferred material layer, Kelvin probe testing to measure the work function of the transferred material layer, atomic force microscopy (AFM) tests to determine the thickness and resolution of the transferred material layer, laser desorption mass spectroscopy to determine impurities, micro-Raman spectroscopy, X-ray fluorescence, or four point probe measurements.

Nondestructive first in-situ tests **270** can include diffracting a laser beam off of a set of lines that form a grating. In this specific embodiment, the grating is deposited along with the organic material atop OLED substrate **15** in a test area of OLED substrate **15** during the radiation thermal transfer process. The grating is illuminated to produce a diffraction pattern, the first order of which is analyzed to yield an indication of the transfer amount and the resolution quality of the transfer. In addition to the quality of the transferred material layer, analyses of the diffraction pattern provided by the grating further yields information regarding the performance of radiation thermal transfer station **124**. Nondestructive first in-situ tests **270** can further include spectroscopic ellipsometry on the transferred material to ascertain transfer layer thickness and density.

Second in-situ tests **280** that are performed on used donor support **265** can include any of the aforementioned nondestructive or destructive tests due to the fact that the used donor support **265** is spent and no longer of use, and can include utilizing the ghost of a transferred diffraction grating that, similar to the nondestructive testing described above, can produce an interference pattern. In addition, comparisons can be made between organic material **70** atop donor **60** and the organic material that is transferred to post-RTT OLED substrate **260** by

comparing parametric data **240** and first set of data **275**. Such combination analysis provides valuable information about how both donor support deposition system **230** and radiation thermal transfer station **124** are behaving. For example, if parametric data **240** describes a suitable layer of organic material atop donor support **72** while first set of data **275** describes an unsuitable thermal transfer of the organic material to OLED substrate **15**, it is likely that the gap **84** provided between OLED substrate **15** and donor **60** during radiation thermal transfer is too large.

Upon undergoing first in-situ test **270**, post-RTT OLED substrate **260** advances to post-RTT processing **290**, which can specifically be chosen to be another thermal transfer of organic material. In one specific example, radiation thermal transfer is utilized to pattern each set of red, green, and blue pixels, in which case post-RTT OLED substrate **260** reenters process flow **200** illustrated in FIG. 5. In the case that no further radiation thermal transfer processing is necessary, post-RTT processing **290** can include more conventional deposition processes such as linear evaporation through a shadow mask or frame mask to deposit additional layers such as an electron-transporting layer or a cathode.

First in-situ tests **270** and second in-situ tests **280** can be performed upon each post-RTT OLED substrate **260** and each used donor support **265**, respectively, that are used during process flow **200** or, alternately, a fraction of post-RTT OLED substrates **260** and used donor supports **265** used during process flow **200** can be tested, e.g., every tenth post-RTT OLED substrate **260** and used donor support **265**. First set of data **275** and second set of data **285** can be further used to alter process parameters downstream to enable compensations to be made. This helps to increase yield and throughput of the radiation thermal transfer process via use of the collected information from first set of data **275** and second set of data **285**.

Turning now to FIG. 6, there is shown a block diagram of one embodiment of a method **300** of making an OLED device in accordance with this invention that corrects for potential defects identified in one processing station by adjusting a subsequent processing step. Method **300** includes the following steps:



In step **310**, an OLED substrate **15** is processed by adding at least one organic layer as described herein. Conveniently, the organic layer(s) are light-emitting layers **35** that are coated by radiation thermal transfer from a donor **60** as described herein.

5           In step **320**, selected in-situ tests are performed on OLED substrate **15** or donor **60**, as described in reference to process flow **200** so as to measure one or more parameters associated with the organic layer (e.g. light-emitting layer **35**). Such tests can include first in-situ test **270** and second in-situ test **280**.

10           The selected in-situ tests are judiciously chosen from a set of either nondestructive or destructive in-situ tests as appropriate, including but not limited to: nondestructive tests such as spectroscopic ellipsometry or diffraction of a laser beam off of a set of lines that form a grating, and destructive testing methods such as photoluminescence or laser desorption mass spectroscopy, Kelvin probe testing, atomic force microscopy, micro-Raman spectroscopy, X-ray fluorescence, or four  
15   point probe measurements. The measurements produce a signal **325** representative of potential defects produced in an OLED device manufactured from OLED substrate **15**. Donor **60** can be tested, e.g. second in-situ test **280** to determine if sufficient organic material **70** was transferred. Testing donor **60** can be performed instead of or in addition to testing OLED substrate **15**.

20           In step **330**, data (e.g. signal **325**) is acquired from the selected in-situ tests and analyzed. Analyses of selected in-situ tests can be performed via an appropriate software program or, alternately, can be analyzed by a process engineer or technician. The analysis of data that occurs in step **330** provides both a set of parametric data (e.g. parametric data **240**, data **275**, or data **285**) that is  
25   stored for access by external process control, process monitoring, and lot binning functions (not shown) as well as information that is utilized for Step **340**.

          In decision step **340**, the results of the data analyses performed in Step **330** are utilized to determine whether donor **60**, OLED substrate **15**, or any coatings thereon are of sufficient quality to continue through process flow **200**. If  
30   yes, Method **300** proceeds to Step **360**. If no, Method **200** proceeds to Step **350**.

In step **350**, donor **60**, OLED substrate **15**, or any coatings thereon have been determined to have defective portions and OLED substrate **15** is withdrawn from process flow **200** or marked or noted as being of inferior quality. Method **300** can thus end.

5                   In step **360**, the results of the data analyses performed in Step **330** are utilized to feed information downstream in process flow **200** and can be utilized to compensate for any undesirable but manageable process variations.

                  In step **370**, a subsequent processing station is adjusted in response to the data signal to change the formation of the subsequent organic layer to  
10   compensate for undesirable but manageable potential defects identified in one processing station as a result of the data analysis performed in Step **330**. For example, if it is determined that the thickness of the light-emitting layer **35** deposited atop OLED substrate **15** within radiation thermal transfer station **124** is 5 nanometers too thick, the subsequent deposition of the electron-transporting  
15   layer **40** in coating station **130** can be reduced by 5 nanometers such that the voltage necessary to drive the OLED display device remains consistent. This helps to increase yield and throughput of the radiation thermal transfer process via use of the data analysis in Step **330**. Method **300** then ends.

                  Turning now to FIG. 7, there is shown a block diagram of another  
20   embodiment of a method **400** of making an OLED device in accordance with this invention that uses a donor to transfer organic material to a substrate. Method **400** includes the following steps:

                  In step **420**, selected in situ tests are performed on donor **60** as described in reference to process flow **200** to determine if there is a defect and  
25   identify the location of such defect in donor **60**. Such tests can include uncoated donor support tests **215** and coated donor tests **235**.

                  The selected in situ tests are judiciously chosen from a set of either nondestructive or destructive in situ tests as appropriate, including but not limited to: nondestructive tests such as spectroscopic ellipsometry or diffraction of a laser  
30   beam off of a set of lines that form a grating, and destructive testing methods such as photoluminescence or laser desorption mass spectroscopy, Kelvin probe testing,

atomic force microscopy, micro-Raman spectroscopy, X-ray fluorescence, or four point probe measurements. The measurements produce a signal **425** representative of potential defects in donor **60** to determine if sufficient organic material **70** will be transferred.

5                   In step **430**, data (e.g. signal **425**) is acquired from the selected in situ tests and analyzed. Analyses of selected in situ tests can be performed via an appropriate software program or, alternately, can be analyzed by a process engineer or technician. The analysis of data that occurs in step **430** provides both a set of parametric data (e.g. parametric data **220** and parametric data **240**) that is  
10 stored for access by external process control, process monitoring, and lot binning functions (not shown) as well as information that is utilized for Step **440**.

                  In decision step **440**, the results of the data analyses performed in Step **430** are utilized to determine whether donor **60** or any coatings thereon are of sufficient quality to continue through process flow **200**. If yes, Method **400**  
15 proceeds to Step **460**. If no, Method **400** proceeds to Step **450**.

                  In step **450**, donor **60** or any coatings thereon have been determined to have defective portions and donor **60** is withdrawn from process flow **200** or marked or noted as being of inferior quality. Method **400** thus ends.

                  Alternatively, donor **60** can be reworked in a further step (not  
20 shown) to correct for the substandard coating of organic material **70**.

                  In step **460**, an OLED substrate is processed by using radiation to transfer organic material **70** from donor **60** to OLED substrate **15**. Step **460** can be adjusted to compensate for undesirable but manageable defective portions of donor **92** that are discovered as a result of the data analysis performed in Step **430**.  
25 For example, if only portions of donor **60** are defective, organic material **70** can be transferred from acceptable portions of donor **60** to OLED substrate **15** to form an organic layer by excluding the identified defective portions of donor **60**. This is particularly convenient when donor **60** is in the form of a continuous web.

                  The invention has been described in detail with particular reference  
30 to certain preferred embodiments thereof, but it will be understood that variations and modifications can be effected within the spirit and scope of the invention.

**PARTS LIST**

10	OLED device
15	substrate
20	anode
25	hole-injecting layer
30	hole-transporting layer
35	light-emitting layer
40	electron-transporting layer
50	cathode
60	donor
62	laser light beam
63	non-transfer surface
65	transfer surface
70	organic material
72	support
74	radiation-absorbing layer
80	thin-film transistor
82	raised surface portion
84	gap
86	receiving surface
90	heat
92	organic layer
100	controlled environment coater
110	unitary housing
112	controlled environment source
114	load lock
116	load lock
120	coating station

**PARTS LIST (con't)**

122	robot
124	radiation thermal transfer station
126	measurement station
128	robot
130	coating station
131	grasping means
134	coating apparatus
138	laser
140	measurement apparatus
146	transparent portion
148	coating apparatus
150	computer
152	data input/output
154	data input/output
156	data input/output
158	data input/output
200	process flow
215	uncoated donor support tests
220	parametric data
225	go/no-go mark
230	donor support deposition system
235	coated donor tests
240	parametric data
245	go/no-go mark
260	post-RTT OLED substrate
265	used donor support
270	in-situ test

**PARTS LIST (con't)**

275	data
280	in-situ test
285	data
290	post-RTT processing
300	method
310	block
320	block
325	signal
330	block
340	decision block
350	block
360	block
370	block
400	method
420	block
425	signal
430	block
440	decision block
450	block
460	block